New Jersey Semi-Conductor Products, Inc.

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GOLD BONDED GERMANIUM DIODE

FEATURES

Low forward voltage drop—low power consumption Thirty years of proven reliability—one million hours mean time between failures (MTBF) Very low noise level Metallurgically bonded

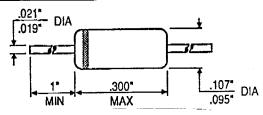
ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage50 VoltsPeak Forward Current500 mAOperating Temperature Range- 65 °C to 85 °CAverage Power Dissipation80 mW

ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min	Max	Unit	T℃	
Peak Inverse Voltage Reverse Current Forward Voltage	PIV Ir Vf	1 mA 20 V 4 mA	50	80 1	ν μΑ ν	25 °C 25 °C 25 °C	

MECHANICAL





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